SOT223 PNP SILICON PLANAR SWITCHING TRANSISTOR

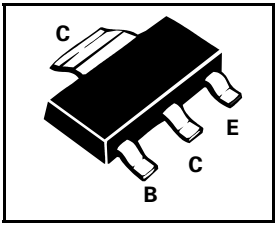
FZT2907
FZT2907A

ISSUE 4 – JUNE 1996 ✪

FEATURES

* 60 Volt V_{CEO}
* Fast switching

PARTMARKING DETAIL – FZT2907 – FZT2907
FZT2907A – FZT2907A



ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	FMMT2907	FMMT2907A	UNIT
Collector-Base Voltage	V_{CBO}	-60		V
Collector-Emitter Voltage	V_{CEO}	-40	-60	V
Emitter-Base Voltage	V_{EBO}	-5		V
Continuous Collector Current	I_C	-600		mA
Power Dissipation at T_{amb}=25°C	P_{tot}	1.5		mW
Operating and Storage Temperature Range	T_j:T_{stg}	-55 to +150		°C

ELECTRICAL CHARACTERISTICS (at T_{amb} = 25°C unless otherwise stated).

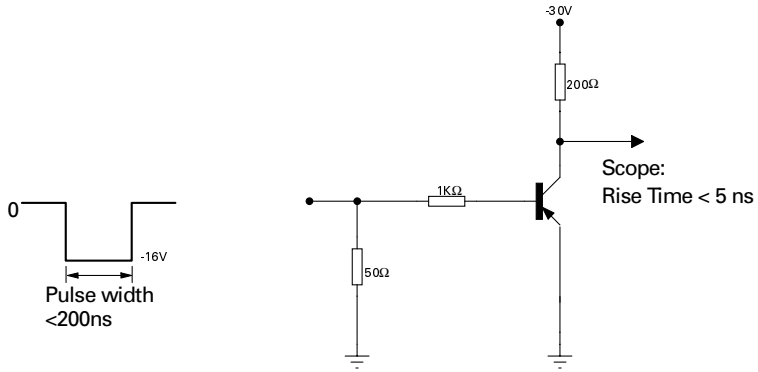
PARAMETER	SYMBOL	FZT2907		FZT2907A		UNIT	CONDITIONS.
		MIN.	MAX.	MIN.	MAX.		
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-40		-60		V	I_C=-10μA, I_E=0
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	-60		-60		V	I_C=-10mA, I_B=0*
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-5		-5		V	I_E=-10μA, I_C=0
Collector-Emitter Cut-Off Current	I_{CEX}		-50		-50	nA	V_{CE}=-30V, V_{BE}=-0.5V
Collector Cut-Off Current	I_{CBO}		-20 -20		-10 -10	nA μA	V_{CB}=-50V, I_E=0 V_{CB}=-50V, I_E=0, T_{amb}=150°C
Base Cut-Off Current	I_B		-50		-50	nA	V_{CE}=-30V, V_{BE}=-0.5V
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$		-0.4 -1.6		-0.4 -1.6	V V	I_C=-150mA, I_B=-15mA* I_C=-500mA, I_B=-50mA*
Base-Emitter Saturation Voltage	$V_{BE(sat)}$		-1.3 -2.6		-1.3 -2.6	V V	I_C=-150mA, I_B=-15mA* I_C=-500mA, I_B=-50mA*
Static Forward Current Transfer Ratio	h_{FE}	35 50 75 100 30	 300 	75 100 100 100 50	 300 		I_C=-0.1mA, V_{CE}=-10V I_C=-1mA, V_{CE}=-10V I_C=-10mA, V_{CE}=-10V I_C=-150mA, V_{CE}=-10V* I_C=-500mA, V_{CE}=-10V*
Transition Frequency	f_T	200		200		MHz	I_C=-50mA, V_{CE}=-20V f=100MHz

*Measured under pulsed conditions. Pulse width=300ms. Duty cycle ≤ 2%

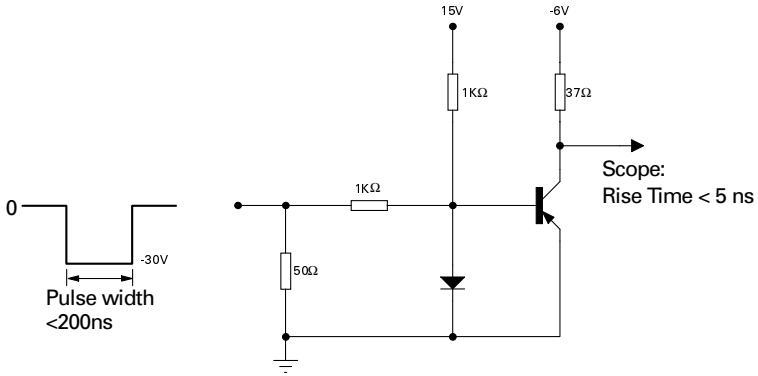
SWITCHING CHARACTERISTICS (at T_{amb} = 25°C unless otherwise stated).

PARAMETER	SYMBOL	FMMT2907		FMMT2907A		UNIT	CONDITIONS.
		MIN.	MAX.	MIN.	MAX.		
Output Capacitance	C_{obo}		8		8	pF	V_{CB}=-10V, I_E=0, f=100KHz
Input Capacitance	C_{ibo}		30		30	pF	V_{BE}=-2V, I_C=0 f=100KHz
Turn On Time	t_{on}		50		50	ns	V_{CE}=-30V I_C=-150mA, I_{B1}=-15mA (See Turn On Circuit)
Turn Off Time	t_{off}		110		110	ns	V_{CE}=-6V, I_C=-150mA I_{B1}= I_{B2}=-15mA (See Turn Off Circuit)

TURN ON TIME – TEST CIRCUIT



TURN OFF TIME – TEST CIRCUIT



littlediode
COMPONENTS FOR ALL

Littlediode supplies new, hard to find or obsolete electronic components and semiconductors all over the world.

With over two million different components listed you are sure to find the part you need.

Feel free to visit us today at our online store:

LittleDiode.com

Looking forward to providing you with the best possible service.